NSN 5961-01-108-8250

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-108-8250 **Inclosure Material:** Glass **Overall Length:** 0.560 inches **Terminal Length:** Between 1.040 inches and 1.250 inches **Overall Diameter:** 0.220 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 7.8 reverse voltage, instantaneous **Current Rating Per Characteristic:** 10.00 milliamperes forward current, total rms nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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